

General Information

The markets of portable communications, computing and video equipment are challenging the semiconductor industry to develop increasingly smaller electronic components. Bourns offers Schottky Barrier Diodes for these applications, in compact chip package 1005 (SOD323) size format, which offer PCB real estate savings and are considerably smaller than most competitive parts. The Schottky Barrier Diodes offer a forward current of 0.5 A with a repetitive peak reverse voltage of 30 V.

Bourns[®] Chip Diodes conform to JEDEC standards, are easy to handle on standard pick and place equipment and their flat configuration minimizes roll away.

Electrical Characteristics (@ T_A = 25 °C Unless Otherwise Noted)

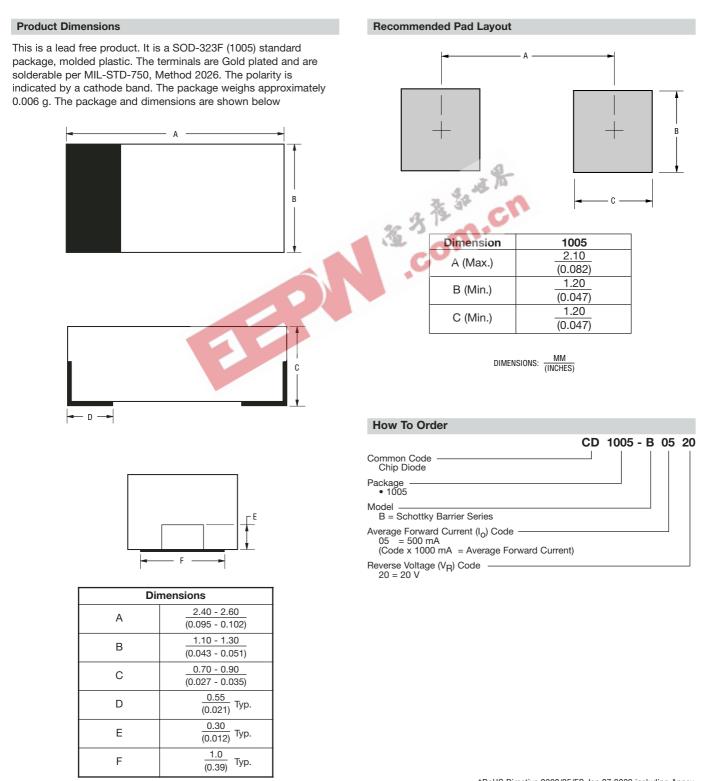
Parameter	Symbol	Min.	Nom.	Max.	Unit
Repetitive Peak Reverse Voltage	VRRM	2	1 3ª CN	30	V
Reverse Voltage	VR	32.3	m.	20	V
Average Forward Rectified Current	lo	C		0.5	А
Maximum Instantaneous Forward Voltage @ IF = 1.0 A	VF		0.45	0.55	V
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load (JEDEC Method)	IFSM			2	A
Forward Voltage (IF = 100 mA)	VF		0.25	0.36	V
Forward Voltage (IF = 500 mA)	VF		0.35	0.47	V
Reverse Current (V _R = 20 V)	IR			100	μA
Capacitance between terminals (f = 1 MHz, and 0 VDC reverse voltage)	Ст		100		pF

Thermal Characteristics (@ T_A = 25 °C Unless Otherwise Noted)

Parameter	Symbol	CD1005-B0520	Unit
Junction Temperature Range	TJ	-40 to +125	°C
Storage Temperature Range	Тята	-40 to +125	°C

CD1005-B0520 – Surface Mount Schottky Barrier Diode

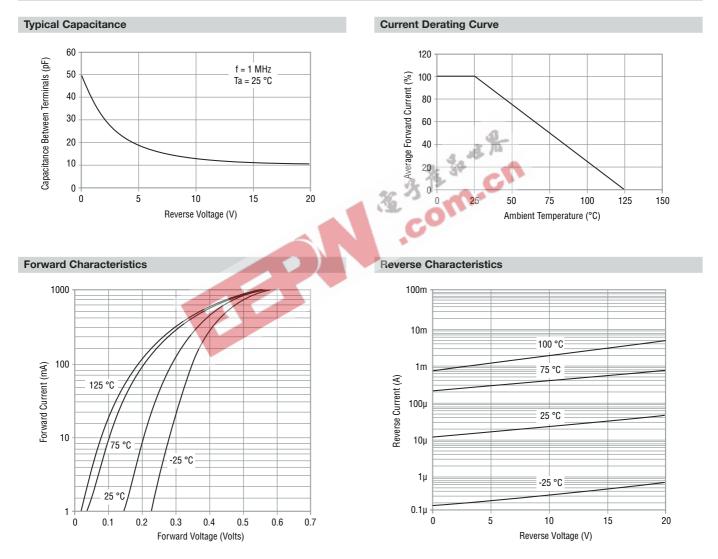
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CD1005-B0520 – Surface Mount Schottky Barrier Diode

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Rating and Characteristic Curves

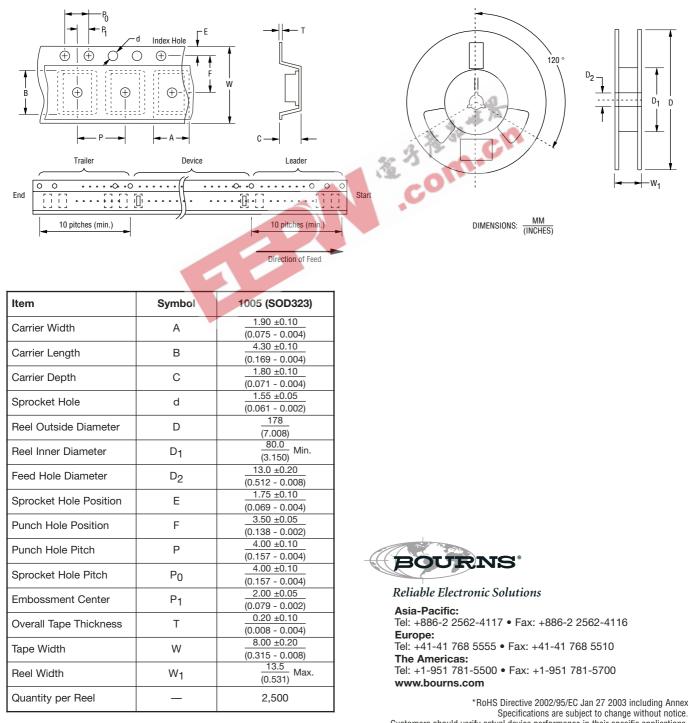


CD1005-B0520 – Surface Mount Schottky Barrier Diode

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Packaging Information

The surface mount product is packaged in an 8 mm x 4 mm tape and reel format per EIA-481 standard.



Customers should verify actual device performance in their specific applications.